24 🛛 V<sub>CC</sub>

23 X

22 Y1

21 Y<sub>2</sub> 20 Y<sub>3</sub>

19 Y<sub>4</sub> 18 Y<sub>5</sub>

17 🛛 Y<sub>6</sub>

16 Y<sub>7</sub>

15 🛛 Y<sub>8</sub>

14 🛛 Y<sub>9</sub>

13 10E2

Q PACKAGE (TOP VIEW)

OE₁ [

 $D_0 [ 2 ]$ 

D<sub>1</sub> [] 3

D<sub>2</sub> [] 4

D<sub>3</sub> [] 5

D₄ []6

D<sub>5</sub> [] 7

D<sub>6</sub> [8

D7 9

D<sub>8</sub> [] 10

D<sub>9</sub> [ 11

GND [ 12

- Function and Pinout Compatible With FCT, F, and AM29827 Logic
- 25-Ω Output Series Resistors Reduce Transmission-Line Reflection Noise
- Reduced V<sub>OH</sub> (Typically = 3.3 V) Versions of Equivalent FCT Functions
- Edge-Rate Control Circuitry for Significantly Improved Noise Characteristics
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)
- Matched Rise and Fall Times
- Fully Compatible With TTL Input and Output Logic Levels
- 12-mA Output Sink Current
  15-mA Output Source Current
- 3-State Outputs

#### description

The CY74FCT2827T 10-bit buffer provides high-performance bus-interface buffering for wide data/address paths or buses carrying parity. This 10-bit buffer has NANDed output-enable ( $\overline{OE}$ ) inputs for maximum control flexibility. The CY74FCT2827T is designed for high-capacitance-load drive capability, while providing low-capacitance bus loading at both inputs and outputs. All inputs have clamp diodes and all outputs are designed for low-capacitance bus loading in the high-impedance state. On-chip termination resistors at the outputs reduce system noise caused by reflections. The CY74FCT2827T can replace the CY74FCT827T to reduce noise in an existing design.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

ТА	PAC	KAGE <sup>†</sup>	SPEED (ns)	ORDERABLE PART NUMBER	TOP-SIDE MARKING		
-40°C to 85°C	QSOP – Q	Tape and reel	4.4	CY74FCT2827CTQCT	FCT2827C		
	QSOP – Q	Tape and reel	8	CY74FCT2827ATQCT	FCT2827A		

**ORDERING INFORMATION** 

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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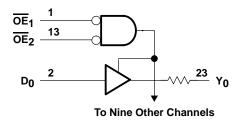
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#### FUNCTION TABLE

	INPUTS		OUTPUT	FUNCTION
OE <sub>1</sub>	OE <sub>2</sub>	D	Y	FUNCTION
L	L	L	L	Transport
L	L	Н	Н	Transparent
Н	Х	Х	Z	2 State
Х	н	Х	Z	3-State

H = High logic level, L = Low logic level, X = Don't care, Z = High-impedance state

#### logic diagram (positive logic)



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range to ground potential	
DC input voltage range	–0.5 V to 7 V
DC output voltage range	–0.5 V to 7 V
DC output current (maximum sink current/pin)	120 mA
Package thermal impedance, $\theta_{JA}$ (see Note 1)	
Ambient temperature range with power applied, T <sub>A</sub>	. −65°C to 135°C
Storage temperature range, T <sub>stg</sub>	. –65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The package thermal impedance is calculated in accordance with JESD 51-7.

#### recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.75	5	5.25	V
VIH	High-level input voltage	2			V
VIL	Low-level input voltage			0.8	V
ЮН	High-level output current			-15	mA
IOL	Low-level output current			12	mA
Τ <sub>Α</sub>	Operating free-air temperature	-40		85	°C

NOTE 2: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation.



## CY74FCT2827T 10-BIT BUFFER WITH 3-STATE OUTPUTS

SCCS045A - MAY 1994 - REVISED SEPTEMBER 2001

PARAMETER		TEST CONDITION	IS	MIN	TYP†	MAX	UNIT
VIK	V <sub>CC</sub> = 4.75,	I <sub>IN</sub> = -18 mA			-0.7	-1.2	V
VOH	V <sub>CC</sub> = 4.75,	I <sub>OH</sub> = -15 mA		2.4	3.3		V
VOL	V <sub>CC</sub> = 4.75,	I <sub>OL</sub> = 12 mA			0.3	0.55	V
R <sub>out</sub>	V <sub>CC</sub> = 4.75,	I <sub>OL</sub> = 12 mA		20	25	40	Ω
V <sub>hys</sub>	All inputs				0.2		V
lj	V <sub>CC</sub> = 5.25 V,	$V_{IN} = V_{CC}$				5	μA
Iн	V <sub>CC</sub> = 5.25 V,	V <sub>IN</sub> = 2.7 V				±1	μA
١ <sub>١L</sub>	V <sub>CC</sub> = 5.25 V,	V <sub>IN</sub> = 0.5 V				±1	μA
los‡	V <sub>CC</sub> = 5.25 V,	V <sub>OUT</sub> = 0 V		-60	-120	-225	mA
loff	$V_{CC} = 0 V,$	V <sub>OUT</sub> = 4.5 V				±1	μA
IOZH	V <sub>CC</sub> = 5.25 V,	V <sub>OUT</sub> = 2.7 V				10	μA
IOZL	V <sub>CC</sub> = 5.25 V,	V <sub>OUT</sub> = 0.5 V				-10	μA
ICC	V <sub>CC</sub> = 5.25 V,	$V_{IN} \le 0.2 V$ ,	$V_{IN} \ge V_{CC} - 0.2 V$		0.1	0.2	mA
∆lcc	$V_{CC} = 5.25 \text{ V}, \text{ V}_{IN} = 3$	3.4 V§, f <sub>1</sub> = 0, Outputs o	pen		0.5	2	mA
ICCD		put switching at 50% du $V_{IN} \le 0.2 \text{ V or } V_{IN} \ge V_{C}$			0.06	0.12	mA MH:
		One bit switching at f <sub>1</sub> = 10 MHz	$ \begin{array}{l} V_{IN} \leq 0.2 \ V \ or \\ V_{IN} \geq V_{CC} - 0.2 \ V \end{array} $		0.7	1.4	
IC#	$V_{CC} = 5.25 V,$	at 50% duty cycle	$V_{IN}$ = 3.4 V or GND		1	2.4	mA
'C"	$\frac{\text{Outputs open,}}{\text{OE}_1 \text{ or OE}_2} = \text{GND}$	Ten bits switching at f <sub>1</sub> = 2.5 MHz	$ \begin{array}{l} V_{IN} \leq 0.2 \ V \ or \\ V_{IN} \geq V_{CC} - 0.2 \ V \end{array} $		1.6	3.2	ШA
		at 50% duty cycle	$V_{IN} = 3.4 \text{ V or GND}$		4.1	13.2	
Ci					5	10	pF
Co					9	12	pF

#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

<sup>†</sup> Typical values are at  $V_{CC}$  = 5 V,  $T_A$  = 25°C.

<sup>‡</sup> Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample-and-hold techniques are preferable to minimize internal chip heating and more accurately reflect operational values. Otherwise, prolonged shorting of a high output can raise the chip temperature well above normal and cause invalid readings in other parametric tests. In any sequence of parameter tests, IOS tests should be performed last.

§ Per TTL-driven input ( $V_{IN}$  = 3.4 V); all other inputs at V<sub>CC</sub> or GND

 $\P$  This parameter is derived for use in total power-supply calculations.

<sup>#</sup>IC  $= I_{CC} + \Delta I_{CC} \times D_H \times N_T + I_{CCD} (f_0/2 + f_1 \times N_1)$ 

Where:

= Total supply current IC.

ICC = Power-supply current with CMOS input levels

- $\Delta I_{CC}$  = Power-supply current for a TTL high input (VIN = 3.4 V)
- $D_{H}$  = Duty cycle for TTL inputs high
- NΤ = Number of TTL inputs at D<sub>H</sub>

I<sub>CCD</sub> = Dynamic current caused by an input transition pair (HLH or LHL)

- = Clock frequency for registered devices, otherwise zero f0
- = Input signal frequency f1
- = Number of inputs changing at f1 N<sub>1</sub>
- All currents are in milliamperes and all frequencies are in megahertz.

 $\parallel$  Values for these conditions are examples of the  $I_{CC}$  formula.

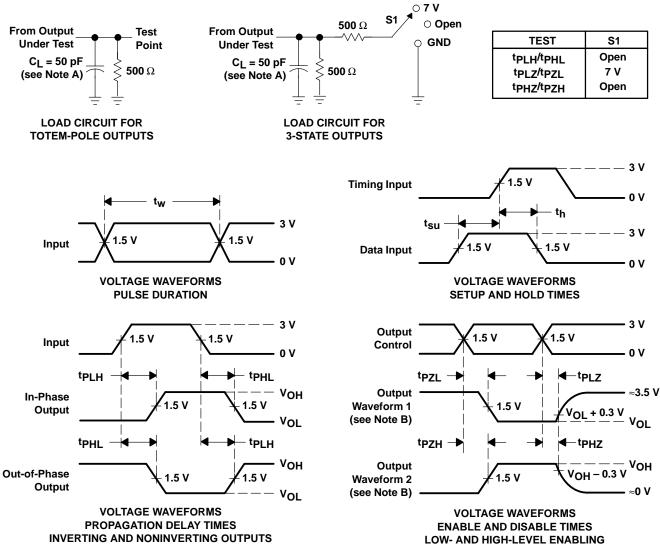


# CY74FCT2827T 10-BIT BUFFER WITH 3-STATE OUTPUTS SCCS045A - MAY 1994 - REVISED SEPTEMBER 2001

## switching characteristics over operating free-air temperature range (see Figure 1)

PARAMETER	FROM	то	TESTIOAD	CY74FCT	2827AT	CY74FCT	2827CT	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	TEST LOAD	MIN	MAX	MIN	MAX	UNIT	
<sup>t</sup> PLH	D	Y	C <sub>L</sub> = 50 pF,	1.5	8	1.5	4.4	ns	
<sup>t</sup> PHL	D	Ι	$R_L = 500 \Omega$	1.5	8	1.5	4.4	115	
<sup>t</sup> PLH	D	Y	C <sub>L</sub> = 300 pF,	1.5	15	1.5	10	ns	
<sup>t</sup> PHL	U	I		$R_L = 500 \Omega$	1.5	15	1.5	10	115
<sup>t</sup> PZH	OE	Y	C <sub>L</sub> = 50 pF,	1.5	12	1.5	7		
<sup>t</sup> PZL	UE	Т	$R_L = 500 \Omega$	1.5	12	1.5	7	ns	
<sup>t</sup> PZH	OE	Y	C <sub>L</sub> = 300 pF,	1.5	23	1.5	14	ns	
<sup>t</sup> PZL	UE	Ι	$R_L = 500 \Omega$	1.5	23	1.5	14	115	
<sup>t</sup> PHZ	OE	Y	C <sub>L</sub> = 5 pF,	1.5	9	1.5	5.7	ns	
<sup>t</sup> PLZ	UE	Т	$R_L = 500 \Omega$	1.5	9	1.5	5.7	115	
<sup>t</sup> PHZ	OE	Y	C <sub>L</sub> = 50 pF,	1.5	9	1.5	6		
<sup>t</sup> PLZ	UE	ř	$R_L = 500 \Omega$	1.5	9	1.5	6	ns	





#### PARAMETER MEASUREMENT INFORMATION

NOTES: A. C<sub>1</sub> includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.

C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms





10-Dec-2020

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
CY74FCT2827ATQCT	ACTIVE	SSOP	DBQ	24	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT2827A	Samples
CY74FCT2827ATQCTG4	ACTIVE	SSOP	DBQ	24	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT2827A	Samples
CY74FCT2827CTQCT	ACTIVE	SSOP	DBQ	24	2500	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	FCT2827C	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

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Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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10-Dec-2020

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# PACKAGE MATERIALS INFORMATION

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### TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CY74FCT2827ATQCT	SSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CY74FCT2827CTQCT	SSOP	DBQ	24	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

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# PACKAGE MATERIALS INFORMATION

30-Dec-2020



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CY74FCT2827ATQCT	SSOP	DBQ	24	2500	853.0	449.0	35.0
CY74FCT2827CTQCT	SSOP	DBQ	24	2500	853.0	449.0	35.0

DBQ (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.

D. Falls within JEDEC MO-137 variation AE.



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